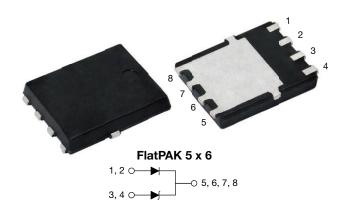


Two-in-One Solution Surface-Mount



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS				
	I _{F(AV)}	3 A		
Standard Rectifier	V_{RRM}	600 V		
Standard nectiller	I _{FSM}	40 A		
	V_F at I_F = 3A (T_J = 125 °C	0.86 V		
Transient Voltage Suppressors	V_{BR}	27 V		
	V_{WM}	23.1 V		
омрр. 3333.3	P _{PPM}	200 W		
T _J max.	175 °C			
Package	FlatPAK 5 x 6			
Circuit configuration	Common cathode			

FEATURES

 Automotive two-in-one solution for rectifier and TRANSZORB® TVS



AUTOMOTIVE GRADE

- Oxide planar chip junction
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- ROHS COMPLIANT HALOGEN FREE
- AEC-Q101 qualified available
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

Secondary protection for sensor units, distributed airbag modules and low power DC / DC converters under power distributer

MECHANICAL DATA

Case: FlatPAK 5 x 6

Molding compound meets UL 94 V-0 flammability rating
Base P/NHM3 - halogen-free, RoHS-compliant, and

AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

HM3 suffix meets JESD 201 class 2 whisker test

TECHNOLOGY	PARAMETER	SYMBOL	R3T2FPHM3	UNIT	
	Device marking code		R3T2FP		
	Maximum repetitive peak reverse voltage	V _{RRM}	600	V	
	Maximum DC forward current	I _{F(AV)} (1)	3	А	
Standard Rectifier	Maximum DC forward current	I _{F(AV)} (2)	2		
	Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	40	А	
Transient Voltage Suppressors	Peak pulse power dissipation with a 10/1000 μs waveform ⁽³⁾	P _{PPM}	P _{PPM} 200		
	Peak pulse current with a 10/1000 µs waveform (3)	I _{PPM}	5.3	Α	
Operating junction temperature range		T _J ⁽⁴⁾	-55 to +175	°C	
Storage temperature range		T _{STG}	-55 to +175	°C	

Notes

- (1) Mounted on 3 x 3 cm aluminum pad area
- (2) Free air mounted on recommended pad area
- (3) Non-repetitive current pulse per Fig.10 and derated above T_A = 25 °C per Fig.8
- $^{(4)}$ The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$



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ELECTRICAL	ELECTRICAL CHARACTERISTICS (T _J = 25 °C unless otherwise noted)								
TECHNOLOGY	PARAMETER	TES	ST CONDITIONS	SYMBOL	MIN.	TYP.	MAX.	UNIT	
		$I_F = 1.5 A$	T _J = 25 °C		1	0.91	-		
	Instantaneous forward voltage	$I_F = 3A$	T _J = 25 °C	V _F ⁽¹⁾	1	0.97	1.1	-	v
	instantaneous forward voltage	I _F = 1.5 A	T _J = 125 °C		-	0.79	-		
Standard Rectifier	$I_F = 3 A$	T _J = 125 °C		ı	0.86	0.98			
Standard Nectine	Reverse current	Rated V _R	T _J = 25 °C	- I _R ⁽²⁾	1	-	10	- 1.1	- μΑ
	neverse current	nateu v _R	T _J = 125 °C		1	13	100		
	Typical reverse recovery time	$I_F = 0.5 A, I$	$I_J = 125 ^{\circ}\text{C}$ - 13 $I_F = 0.5 \text{A}, I_R = 1.0 \text{A}, I_{rr} = 0.25 \text{A}$ t_{rr} - 1.5	-	μs				
	Typical junction capacitance	4.0 V, 1 MHz		CJ	-	19	-	pF	
	Breakdown Voltage (3)	I _T =1.0 mA		V_{BR}	25.7	27.0	28.4	V	
	Stand-off Voltage			V_{WM}	1	23.1	0.86 0.98 - 10 μA 1.5 - μs 19 - pF 27.0 28.4 V 23.1 - V - 0.5 μA		
Transient Voltage	Maximum Reverse Leakage	Rated V _{WM}		I_D	-	-	0.5	V 8 μA ρF 4 V V 5 μA 5 V ρF	
Suppressors	Maximum Clamping Voltage	$I_{PPM} = 5.3 A$	A, 10/1000 µs waveform	V_{C}	1	19 - pF 27.0 28.4 V 23.1 - V - 0.5 μA - 37.5 V			
Suppressors	Typical junction capacitance	0 V		CJ		330		pF	
	Typical junction capacitance	23.1 V		CJ		95		pF	

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: pulse width ≤ 5 ms

⁽³⁾ Pulse test: $t_p \le 50$ ms

IMMUNITY TO E (T _A = 25 °C unless	ELECTRICAL STATIC DISCHARG otherwise noted)	E TO THE FOLLOWIN	G STANDA	ARDS	
STANDARD	TEST TYPE	TEST CONDITIONS	SYMBOL	CLASS	VALUE
AEC-Q101-001	Human body model (contact mode)	$C = 100 \text{ pF}, R = 1.5 \text{ k}\Omega$		НЗВ	> 8 kV
AEC-Q101-005	Charged device model (CDM)	V = 500 V	. ,	C3	> 1 kV
IEC 61000-4-2 (2)	Contact mode	C = 150 pF, R = 330 Ω	V _C	4	> 8 kV
	Air-discharge mode (1)	C = 150 pF, R = 330 Ω]	4	> 15 kV

Notes

(1) Immunity to IEC 61000-4-2 air discharge mode has a typical performance > 30 kV

(2) System ESD standard

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER SYMBOL TYP. MAX. UNIT						
Thermal registance per diade	R _{0JA} (1)(2)	80	-	°C/W		
Thermal resistance per diode	R _{θJM} ⁽³⁾	3.0	4.0	C/VV		

Notes

- $^{(1)}$ The heat generated must be less than thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$
- (2) Thermal resistance junction-to-ambient to follow JEDEC® 51-2A, device mounted on FR4 PCB, 2 oz., standard footprint
- (3) Thermal resistance junction-to-mount to follow JEDEC® 51-14 transient dual interface test method (TDIM)

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
R3T2FPHM3/I (1)	0.10	I	6000	13" diameter plastic tape and reel		

Note

(1) AEC-Q101 qualified



RATINGS AND CHARACTERISTICS CURVES FOR RECTIFIERS (T_A = 25 °C unless otherwise noted)

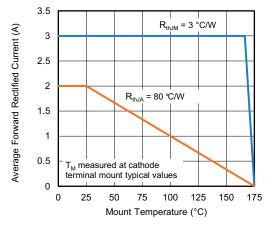


Fig. 1 - Maximum Forward Derating Curve

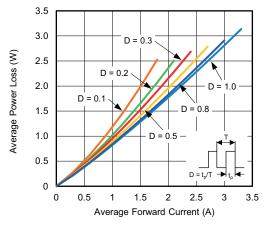


Fig. 2 - Forward Power Loss Characteristics

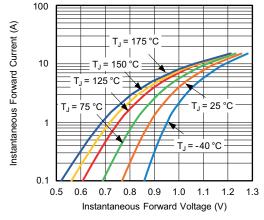


Fig. 3 - Typical Instantaneous Forward Characteristics

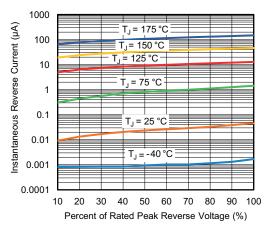


Fig. 4 - Typical Reverse Leakage Characteristics

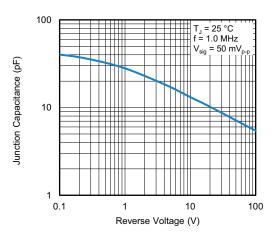


Fig. 5 - Typical Junction Capacitance

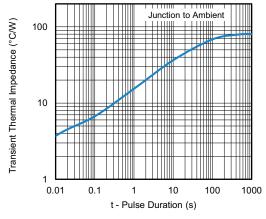


Fig. 6 - Typical Transient Thermal Impedance



RATINGS AND CHARACTERISTICS CURVES FOR TVS (T_A = 25 °C unless otherwise noted)

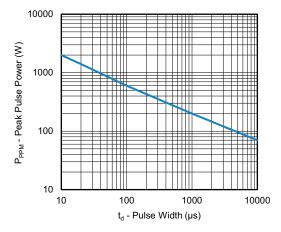


Fig. 7 - Peak Pulse Power Derating Curve

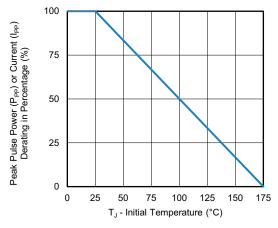


Fig. 8 - Pulse Power or Current vs. Initial Junction Temperature

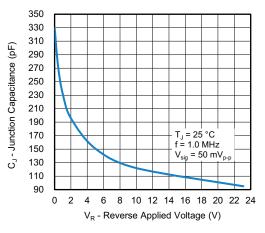


Fig. 9 - Typical Junction Capacitance

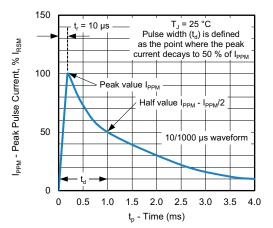
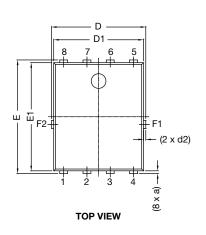


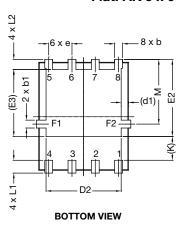
Fig. 10 - Pulse Waveform

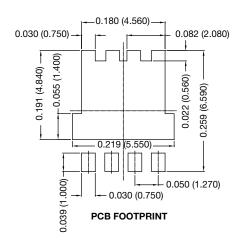


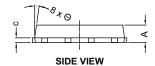
PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

FlatPAK 5 x 6









DIM	INCHES			MILLIMETERS			
DIM.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
Α	0.035	0.039	0.043	0.89	0.99	1.09	
(a)	-	0.006	-	-	0.15	-	
b	0.013	0.017	0.020	0.32	0.43	0.52	
b1	0.013	0.017	0.020	0.32	0.43	0.52	
С	0.008	-	0.014	0.20	-	0.35	
D	0.197	0.203	0.209	5.00	5.15	5.30	
D1	0.189	0.193	0.197	4.80	4.90	5.00	
D2	0.154	0.161	0.169	3.90	4.10	4.30	
(d1)	-	0.016	-	-	0.40	-	
(d2)	-	0.005	-	-	0.125	-	
Е	0.238	0.244	0.250	6.05	6.20	6.35	
E1	0.228	0.232	0.236	5.80	5.90	6.00	
E2	0.157	0.165	0.173	4.00	4.20	4.40	
(E3)	-	0.144	-	-	3.65	-	
е		0.050 BSC			1.27 BSC		
(K)	0.039	-	-	1.00	-	-	
L1	0.019	-	0.043	0.48	-	1.10	
L2	0.012	-	0.031	0.30	-	0.80	
М	0.128	0.138	0.148	3.25	3.50	3.75	
Θ	0°	-	10°	0°	-	10°	

Notes

- Dimensioning and tolerancing per ASME Y14.5-2009
- Dimensions D1 and E1 do not include mold flash or gate burrs
- Dimension (XX) means reference only



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